SARDAR PATEL UNIVERSITY

M. Sc. (Semester – IV) CBCS Examination Thursday, 7th April 2016 2.30 p.m. to 5.30 p.m.

PS04CINC02 Solid State Chemistry (Inorganic Chemistry)

Note : Fig	gures to the right indicate full marks. Total Marks: 70)
(Useful co	onstants are, $h = 6.63 \times 10^{-34} \text{ J.s.}$, $R = 1.987 \text{ cal. K}^{-1} \cdot \text{mol}^{-1}$, $k = 1.38 \times 10^{-23} \text{ J. K}^{-1}$, $k = 0.695 \text{ cm}^{-1}$, $k = 8.625 \times 10^{-5} \text{ eV.K}^{-1}$, $N_A = 6.023 \times 10^{23} \text{ molecule}^{-1}$)	
Q.1 Se	elect the correct answer from the alternatives given below to the each question;	[08]
[i]		lool
	(a) copper, (b) caesium fluoride, (c) silicon carbide (d) magnesium oxide	
[ii]	i] A <i>n</i> -type semiconductor is formed when Gallium is doped with;	
	(a) boron (b) aluminium (c) arsenic (d) silicon	
[iii	i] A certain metal having a molar mass of 0.184 kg crystallises is BCC lattice. Its density is 19300 kg.m ⁻³ . The radius of the metal atom (in metres) is;	
	(a) 1.73×10^{-10} , (b) 3.71×10^{-10} , (c) 2.74×10^{-10} , (d) 1.37×10^{-10}	
[iv	When X-ray of wavelength 1.542×10^{-10} m strike a crystal whose planes are 9.51×10^{-10} m a part, first order diffraction is observed. The glacing angle is;	
	(a) 51°4' (b) 41°5', (c) 45°1', (d) 54°1'	
[v]	Which of the following is true for Frenkel defects?	
	(a) they occur in pure alkali halides,(b) they do not occur in silver halides,(c) density of crystal does not change,(d) F-centres arise in such crystal	
[vi]		
	(a) nucleation (b) growth (c) contact surface area (d) all of above	
[vii	In photoconductor, semiconductor must show dependent conductivity; (a) temperature, (b) photon, (c) hole, (d) phonon	
[viii	• •	
	(a) $a = b = c$, $\alpha = \beta = 90^{\circ}$, $\gamma = 120^{\circ}$ (b) $a = b \neq c$, $\alpha = \gamma = 90^{\circ}$, $\beta \neq 90^{\circ}$ (c) $a = b = c$, $\alpha = \beta = \gamma \neq 90^{\circ}$ (d) $a = b = c$, $\alpha = \beta = \gamma = 90^{\circ}$	

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Q.2 Answer the following in short; (ANY SEVEN)

[14]

- [a] Justify $\tilde{6} = \overline{3}$.
- [b] Using appropriate figure, explain point group 6/m 2/m 2/m.
- [c] Explain "Density of crystal decreases by introducing Frenkel defects".
- [d] Enlist drawbacks of free electron theory.
- [e] Explain Fermi energy, ionization potential.
- [f] How to eliminate induction period in solid reaction.
- [g] Explain, m < m* condition in decomposition reactions.
- [h] Discuss "in phase" situation in X-ray diffraction.
- [i] Justify "X-ray diffraction is used to find positions of heavier elements in solids".
- Q.3 [a] [i] Considering an example of NaCl crystal, derive following relation for [03] Schottky defects.

$$\log(N_V) = \log(N) - \frac{\Delta H}{2 R T}$$

- [ii] A metal (atomic mass = 40 g.mol⁻¹) in FCC has an edge length of 5.6×10^{-10} m. If it has 0.75% Schottky defects, Calculate its density (in Kg.m⁻³).
- [b] [i] Write a note on "Tetragonal crystal system". [03]
 - [ii] Explain extrinsic symmetry along with definition of symmetry. [03]

<u>OR</u>

- [b] [i] Write a note on "Roto-reflection". [03]
 - [ii] Explain F-centres and self-interstitial defects. [03]
- Q.4 [a] Define semiconductors. Discuss extrinsic semiconductors in detail with [06] example.
 - [b] Draw dispersion curves and explain allowed and forbidden regions of first Brillouin zone between $k = -\pi/a$ to $k = \pi/a$.

<u>OR</u>

- [b] [i] Considering group IV elements, explain why Eg decreases with [03] increase in bond length.
 - [ii] Discuss effect of temperature on carrier concentration and [03] conductivity.
- Q.5 [a] [i] Considering Wagner mechanism for following solid state reaction, [03] explain factors affecting the reactions.

$$4 \text{ MgO}_{(s)} + 4 \text{ Al}_2\text{O}_{3 (s)} \rightarrow 4 \text{ MgAl}_2\text{O}_{4 (s)}$$

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- Q.5 [a] [ii] Explain sol-gel method for preparation of solid. Discuss effect of pH [03] during sol-gel process.

 [b] [i] With appropriate examples explain synthetic metals. [03]
 - [ii] What are inorganic phosphors? Explain Stokes shift. [03]

<u>OR</u>

- [b] [i] Justify "LASERS are high flux light source". [03]
 - [ii] With the help of graphs on variation of degree of decomposition as a function of time, explain various types of solid state reactions.
- Q.6 [a] [i] Enlists advantages of neutron and X-ray diffraction. [03]
 - [ii] Considering an example of NaCl crystal and $\lambda = 1.541$ Å and d₁₁₁ = 3.255 Å. Prove that first, second, third and fourth order reflections are possible while fifth order reflection is not possible.
 - [b] At 20 °C, Fe is body centered cubic, Z = 2, a = 2.866 Å. At 950 °C, Fe is face centered cubic, Z = 4, a = 3.656 Å. At 1425 °C, Fe is again body centered cubic, Z = 2, a = 2.940 Å. At each temperature, calculate (a) the density of iron, (b) the metallic radius of iron atoms. [Atomic weight of Fe = 55.93 g.mol⁻¹]

<u>OR</u>

- [b] [i] The density of LiF is 2.601 g.cm⁻³. The (1 1 1) first order reflection in the X-ray diffraction from LiF occurs at 8°44' when X-ray of wavelength 70.8 pm (1 pm = 10⁻¹² m) are used. If there are four LiF molecules per unit cell, Calculate Avogadro's number. LiF crystallises in the cubic system. [Li = 6.939 g.mol⁻¹, F = 18.998 g. mol⁻¹].
 - [ii] The (1 1 1) reflection in the powder pattern of KCl has zero intensity but in the powder of KF it is fairly strong. Explain.

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